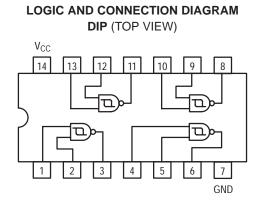
Quad 2-Input Schmitt Trigger NAND Gate

The SN74LS132 contains four 2-Input NAND Gates which accept standard TTL input signals and provide standard TTL output levels. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. Additionally, they have greater noise margin than conventional NAND Gates.

Each circuit contains a 2-input Schmitt trigger followed by a Darlington level shifter and a phase splitter driving a TTL totem pole output. The Schmitt trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive and negative-going transitions. This hysteresis between the positive-going and negative-going input thresholds (typically 800 mV) is determined internally by resistor ratios and is essentially insensitive to temperature and supply voltage variations. As long as one input remains at a more positive voltage than V_{T+} (MAX), the gate will respond to the transitions of the other input as shown in Figure 1.



GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Мах	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{ОН}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



ON Semiconductor Formerly a Division of Motorola http://onsemi.com

LOW POWER SCHOTTKY



PLASTIC N SUFFIX CASE 646



ORDERING INFORMATION

Device	Package	Shipping		
SN74LS132N	14 Pin DIP	2000 Units/Box		
SN74LS132D	14 Pin	2500/Tape & Reel		

Semiconductor Components Industries, LLC, 1999
December, 1999 – Rev. 6

SN74LS132

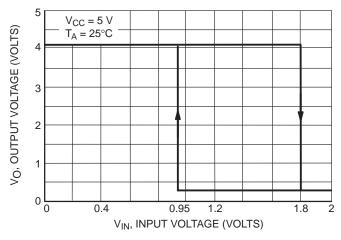


Figure 1. V_{IN} versus V_{OUT} Transfer Function

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DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)						
		Limits				

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
V _{T+}	Positive-Going Threshold Voltage	1.5		2.0	V	$V_{CC} = 5.0 V$
V _{T-}	Negative-Going Threshold Voltage	0.6		1.1	V	$V_{CC} = 5.0 V$
$V_{T +} - V_{T-}$	Hysteresis	0.4	0.8		V	$V_{CC} = 5.0 V$
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$
V _{OH}	Output HIGH Voltage	2.7	3.4		V	V_{CC} = MIN, I_{OH} = -400 μ A, V_{IN} = V_{IL}
M			0.25	0.4	V	V_{CC} = MIN, I_{OL} = 4.0 mA, V_{IN} = 2.0 V
V _{OL}	Output LOW Voltage		0.35	0.5	V	V_{CC} = MIN, I_{OL} = 8.0 mA, V_{IN} = 2.0 V
I _{T+}	Input Current at Positive-Going Threshold		-0.14		mA	V_{CC} = 5.0 V, V_{IN} = V_{T+}
I _{T-}	Input Current at Negative-Going Threshold		-0.18		mA	$V_{CC} = 5.0 \text{ V}, \text{ V}_{IN} = \text{V}_{T-}$
				20	μA	$V_{CC} = MAX, V_{IN} = 2.7 V$
lih	Input HIGH Current			0.1	mA	$V_{CC} = MAX, V_{IN} = 7.0 V$
IIL	Input LOW Current			-0.4	mA	$V_{CC} = MAX, V_{IN} = 0.4 V$
I _{OS}	Output Short Circuit Current (1)	-20		-100	mA	$V_{CC} = MAX, V_{OUT} = 0 V$
ICC	Power Supply Current Total, Output HIGH		5.9	11	mA	V _{CC} = MAX, V _{IN} = 0 V
	Total, Output LOW		8.2	14	mA	$V_{CC} = MAX, V_{IN} = 4.5 V$

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25° C)

		Limits				
Symbol	Parameter	Min	Тур	Мах	Unit	Test Conditions
t _{PLH}	Turn-Off Delay, Input to Output			22	ns	V _{CC} = 5.0 V
t _{PHL}	Turn-On Delay, Input to Output			22	ns	C _L = 15 pF

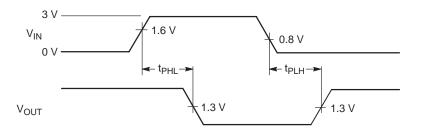
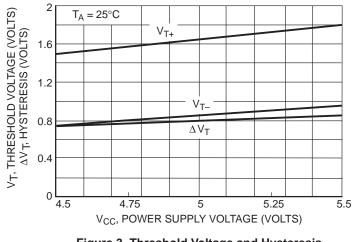
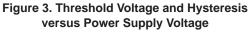
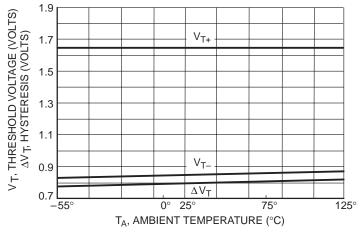


Figure 2. AC Waveforms









SN74LS132

PACKAGE DIMENSIONS

N SUFFIX

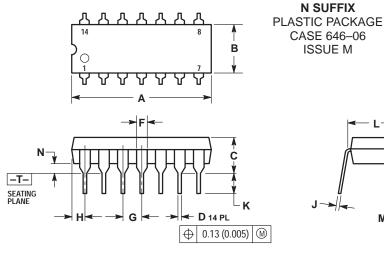
ISSUE M

D SUFFIX

PLASTIC SOIC PACKAGE

CASE 751A-03

ISSUE F



-A-

G

-T-

SEATING PLANE

F

D 14 PL

-R-

T

⊕ 0.25 (0.010) M T B S A S

κ

P 7 PL

C

⊕ 0.25 (0.010) M B M

R X 45 9

Μ



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

CONTROLLING DIMENSION: INCH. DIMENSION L TO CENTER OF LEADS WHEN

3

FORMED PARALLEL. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.715	0.770	18.16	18.80	
В	0.240	0.260	6.10	6.60	
С	0.145	0.185	3.69	4.69	
D	0.015	0.021	0.38	0.53	
F	0.040	0.070	1.02	1.78	
G	0.100 BSC		2.54 BSC		
Н	0.052	0.095	1.32	2.41	
J	0.008	0.015	0.20	0.38	
К	0.115	0.135	2.92	3.43	
L	0.290	0.310	7.37	7.87	
М		10°		10°	
N	0.015	0.039	0.38	1.01	

NOTES DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: MILLIMETER 3. DIMENSIONS A AND B DO NOT INCLUDE

MOLD PROTRUSION. 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006)

PER SIDE.

5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION

	MILLIN	IETERS	INCHES					
DIM	MIN	MAX	MIN	MAX				
Α	8.55	8.75	0.337	0.344				
В	3.80	4.00	0.150	0.157				
С	1.35	1.75	0.054	0.068				
D	0.35	0.49	0.014	0.019				
F	0.40	1.25	0.016	0.049				
G	1.27	BSC	0.050 BSC					
J	0.19	0.25	0.008	0.009				
K	0.10	0.25	0.004	0.009				
Μ	0 °	7°	0 °	7°				
Р	5.80	6.20	0.228	0.244				
R	0.25	0.50	0.010	0.019				

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